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74LCXH245 Low Voltage Bidirectional Transceiver with Bushold

General Description

Features

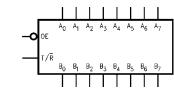
- 5V tolerant control inputs
- 2.3V-3.6V V_{CC} specifications provided
- 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 µA I_{CC} max
- Power down high impedance outputs
- \blacksquare ±24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- Bushold on inputs eliminates the need for external pull-up/pull-down resistors
- ESD performance: Human body model > 2000V Machine model > 200V

Ordering Code:

buffers with 3-ST ented application (2.5V and 3.3V) mines the directic input disables bo high impedance s The LCXH245 is nology to achieve CMOS low power include active bu	ontains eight non-in ATE outputs and is s. The device is des V_{CC} applications. T n of data flow throug h the A and B ports tate. fabricated with an ac high speed operati dissipation. The LC shold circuitry, elim esistors to hold unu- gic level.	averting bidirectional intended for bus ori- igned for low voltage he T/R input deter- h the device. The OE by placing them in a dvanced CMOS tech- on while maintaining XH16244 data inputs inating the need for used or floating data	 Features 5V tolerant control inputs 2.3V-3.6V V_{CC} specifications provided 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max Power down high impedance outputs ±24 mA output drive (V_{CC} = 3.0V) Implements patented noise/EMI reduction circuitry Latch-up performance exceeds 500 mA Bushold on inputs eliminates the need for external pull-up/pull-down resistors ESD performance: Human body model > 2000V Machine model > 200V
Order Number	Package Number		Package Description
	M20B	20-Lead Small Outline	Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
'4LCXH245WM	-		Package (SOP), EIAJ TYPE II, 5.3mm Wide
	M20D		I AURAYE (OUI), LIAJ I I FL II, J.JIIIII WILE
74LCXH245WM 74LCXH245SJ 74LCXH245MSA	M20D MSA20		Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Pin Descriptions

Pin Names	Description
OE	Output Enable Input
T/R	Transmit/Receive Input
A ₀ -A ₇	Side A Inputs or 3-STATE Outputs (Bushold)
B ₀ -B ₇	Side B Inputs or 3-STATE Outputs (Bushold)

Connection Diagram

			-
t/R —		20	— v _{cc}
A ₀ —	2	19	- OE
A ₁ —	3	18	— в _о
A ₂ —	4	17	— В ₁
A3 —	5	16	— в ₂
A4 —	6	15	— В _З
А ₅ —	7	14	— В ₄
А ₆ —	8	13	— В ₅
A ₇ —	9	12	— ^в 6
GND —	10	11	— B ₇

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Truth Table

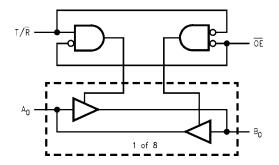
74LCXH245

Inp	outs	
OE	T/R	Outputs
L L		Bus $B_0 - B_7$ Data to Bus $A_0 - A_7$
L H		Bus $A_0 - A_7$ Data to Bus $B_0 - B_7$
н х		HIGH Z State on $A_0 - A_7$, $B_0 - B_7$ (Note 1)

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial Z = High Impedance

Note 1: Unused bus terminals during HIGH Z State must be held HIGH or LOW.

Logic Diagram



Symbol	Parameter	Value	Conditions	Units	
V _{CC}	Supply Voltage	-0.5 to +7.0		V	
VI	T/R, OE	0.5 to +7.0		V	
	I/O Ports	-0.5 to V _{CC} + 0.5			
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V	
		-0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 3)	v	
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA	
I _{OK}	DC Output Diode Current	-50	V _O < GND	m۸	
		+50	V _O > V _{CC}	mA	
I _O	DC Output Source/Sink Current	±50		mA	
I _{CC}	DC Supply Current per Supply Pin	±100		mA	
I _{GND}	DC Ground Current per Ground Pin	±100		mA	
T _{STG}	Storage Temperature	-65 to +150		°C	

Recommended Operating Conditions (Note 4)

Symbol	Parameter	Min	Max	Units	
V _{CC}	Supply Voltage	2.0	3.6	V	
		Data Retention	1.5	3.6	v
VI	Input Voltage		0	V _{CC}	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	v
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±24	
		V _{CC} = 2.7V - 3.0V		±12	mA
		$V_{CC} = 2.3V - 2.7V$		±8	
T _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, $V_{IN} = 0.8V - 2.0V$, $V_{CC} = 3.0V$		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_{O} Absolute Maximum Rating must be observed.

Note 4: Floating or unused control inputs must be HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
Symbol	Faidilielei	Conditions	(V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		v
			2.7 – 3.6	2.0		Ň
V _{IL}			2.3 – 2.7		0.7	v
			2.7 - 3.6		0.8	Ň
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -8 \text{ mA}$	2.3	1.8		v
		I _{OH} = -12 mA	2.7	2.2		
		I _{OH} = -18 mA	3.0	2.4		
		I _{OH} = -24 mA	3.0	2.2		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		I _{OL} = 8mA	2.3		0.6	v
		I _{OL} = 12 mA	2.7		0.4	
		I _{OL} = 16 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	
l _l	Input Leakage Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		±5.0	μΑ

74LCXH245

DC Electrical Characteristics (Continued)

$T_A = -40^{\circ}C$ to $+85^{\circ}C$ ٧_{cc} Symbol Parameter Conditions Units (V) Min Max Bushold Input Minimum $V_{IN} = 0.7V$ 45 II(HOLD) 2.3 Drive Hold Current $V_{IN} = 1.7V$ -45 μΑ $V_{IN} = 0.8V$ 75 3.0 $V_{IN} = 2.0V$ -75 Bushold Input Over-Drive (Note 6) 300 I_{I(OD)} 2.7 Current to Change State (Note 7) -300 μΑ 450 (Note 6) 3.6 -450 (Note 7) 3-STATE I/O Leakage 2.3 - 3.6 ±5.0 $V_0 = V_{CC} \text{ or } GND$ μΑ I_{OZ} Quiescent Supply Current $V_I = V_{CC}$ or GND 2.3 - 3.6 10 I_{CC} μΑ $3.6V \le V_I, V_O \le 5.5V$ (Note 5) 2.3 - 3.6 ±10 ΔI_{CC} Increase in I_{CC} per Input $V_{IH} = V_{CC} - 0.6V$ 2.3 - 3.6 500 μΑ

Note 5: Outputs disabled or 3-STATE only.

Note 6: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 7: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

AC Electrical Characteristics

		$\mathbf{T}_{\mathbf{A}}=-40^{\circ}\mathbf{C}$ to $+85^{\circ}\mathbf{C},\mathbf{R}_{\mathbf{L}}=500\Omega$						
Symbol	Parameter	V _{CC} = 3.	$3V \pm 0.3V$	V _{CC} =	= 2.7V	V _{CC} = 2	$.5V \pm 0.2V$	Units
		C _L = 50 pF		C _L = 50 pF		C _L = 30 pF		Units
		Min	Max	Min	Max	Min	Мах	1
t _{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	ns
t _{PLH}	A _n to B _n or B _n to A _n	1.5	7.0	1.5	8.0	1.5	8.4	
t _{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	
t _{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	ns
t _{PLZ}	Output Disable Time	1.5	7.5	1.5	8.5	1.5	9.0	ns
t _{PHZ}		1.5	7.5	1.5	8.5	1.5	9.0	ns
t _{OSHL}	Output to Output Skew		1.0					ns
t _{OSLH}	(Note 8)		1.0					115

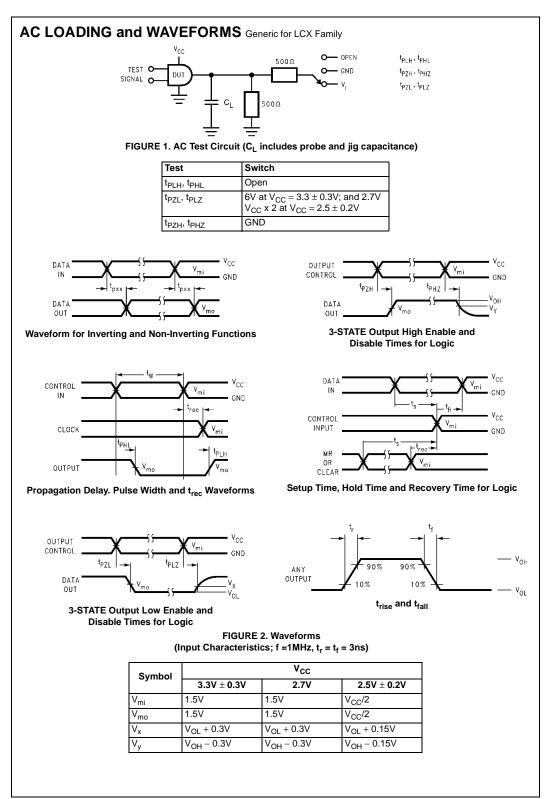
Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSLI}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

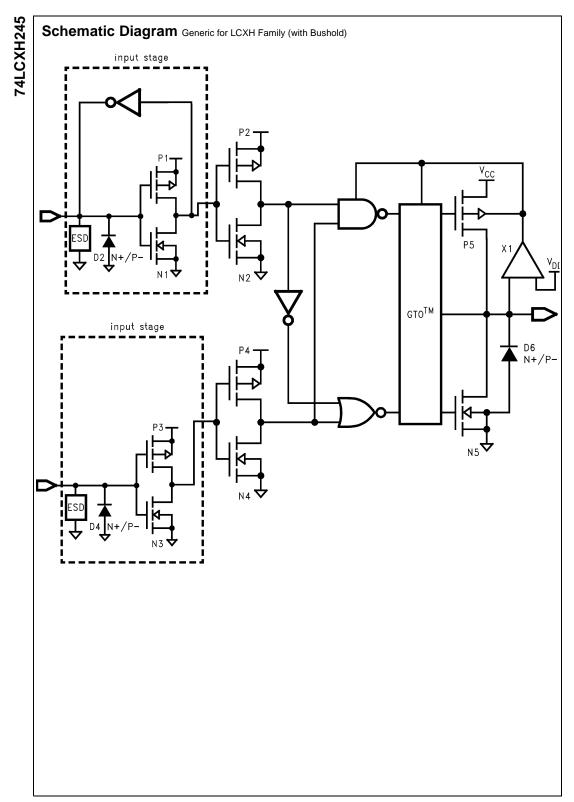
Symbol	Parameter	Conditions	v _{cc}	$T_A = 25^{\circ}C$	Units
Cymbol	i arameter	Conditiona	(V)	Typical	onita
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, \text{ V}_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	25	pF

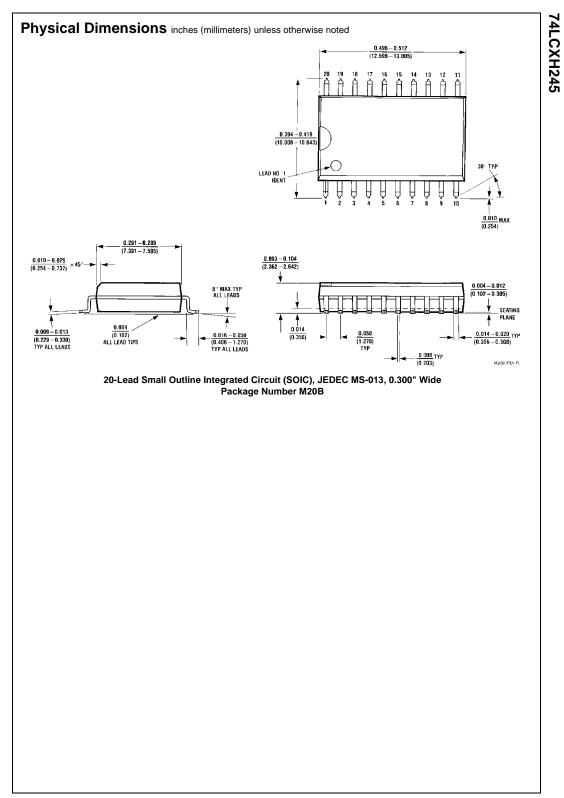


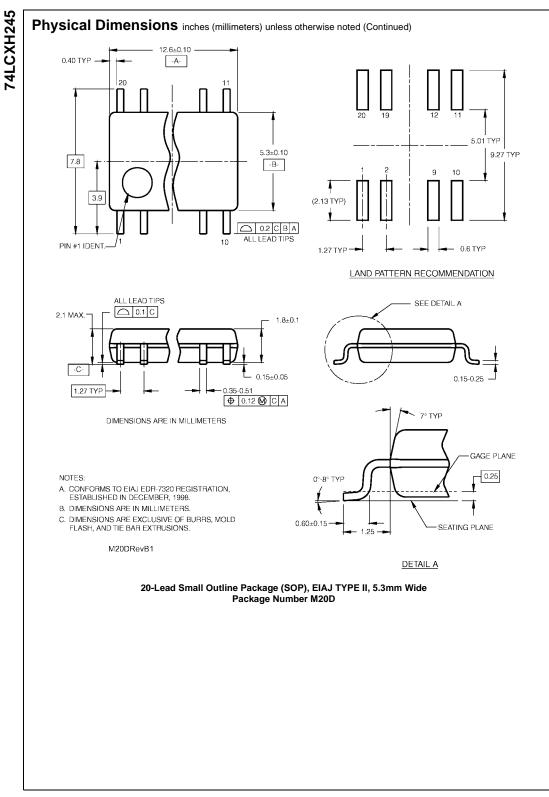
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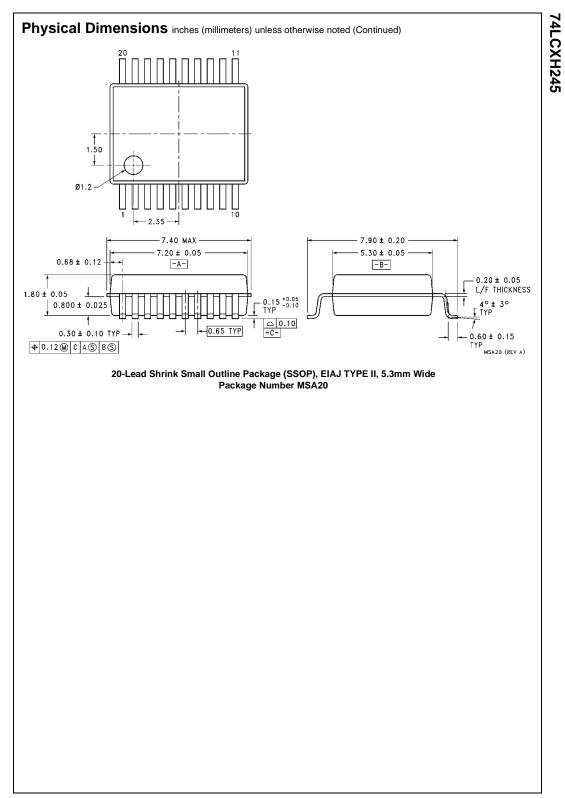


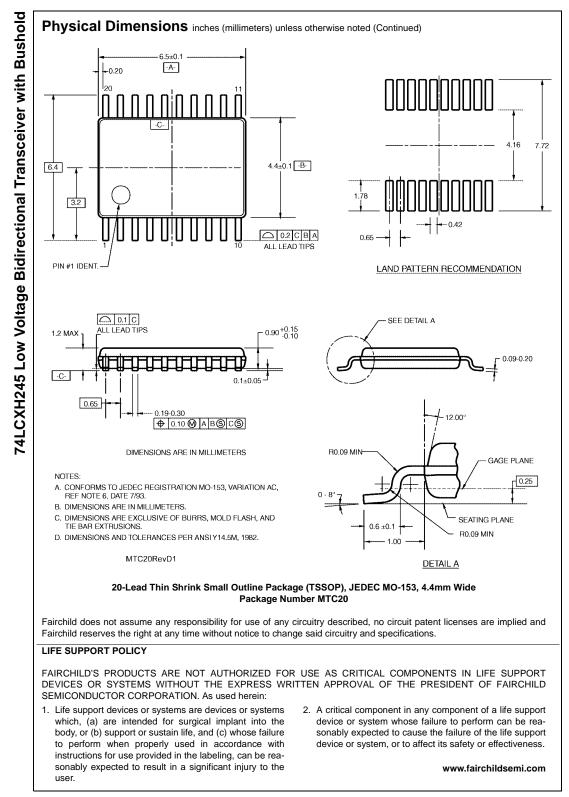
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